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# 2SD1420

# Silicon NPN Epitaxial



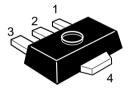
ADE-208-1151 (Z) 1st. Edition Mar. 2001

# **Application**

Low frequency power amplifier

### **Outline**

#### **UPAK**



- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector (Flange)

# 2SD1420

# **Absolute Maximum Ratings** $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{\text{CBO}}$	180	V
Collector to emitter voltage	$V_{\text{CEO}}$	120	V
Emitter to base voltage	$V_{EBO}$	5	V
Collector current	I <sub>c</sub>	1.5	A
Collector peak current	i <sub>C(peak)</sub> *1	3	A
Collector power dissipation	P <sub>c</sub> *2	1	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW ≤ 10 ms, Duty cycle ≤ 20%

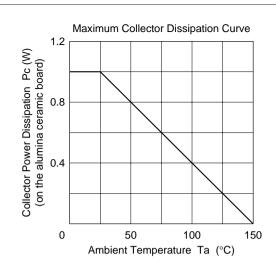
2. Value on the alumina ceramic board (12.5 x 20 x 0.7 mm)

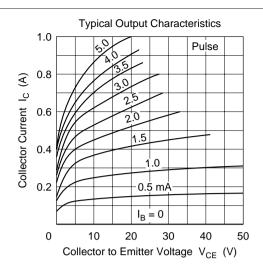
# **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

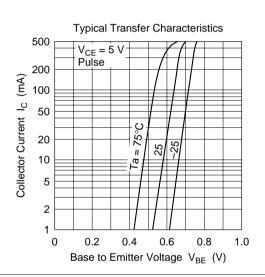
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	180	_	_	V	$I_C = 1 \text{ mA}, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	120	_	_	V	$I_{C}$ = 10 mA, $R_{BE}$ = $\infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	V	$I_{E} = 1 \text{ mA}, I_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	10	μΑ	V <sub>CB</sub> = 160 V, I <sub>E</sub> = 0
DC current transfer ratio	h <sub>FE1</sub> *1	60	_	320		$V_{CE} = 5 \text{ V}, I_{C} = 0.15 \text{ A}$
	h <sub>FE2</sub>	30	_	_		$V_{CE} = 5 \text{ V}, I_{C} = 0.5 \text{ A}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	1.0	V	$I_{\rm C}$ = 0.5 A, $I_{\rm B}$ = 50 mA, Pulse
Base to emitter voltage	$V_{BE}$	_	_	0.9	V	$V_{CE} = 5 \text{ V}, I_{C} = 0.15 \text{ A}, \text{ Pulse}$

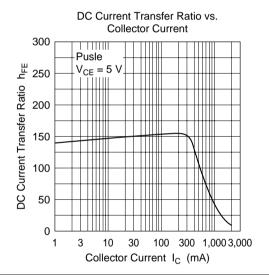
Note: 1. The 2SD1420 is grouped by  $h_{\text{FE1}}$  as follows.

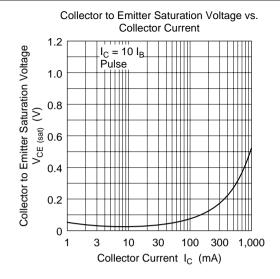
Mark	EA	EB	EC
h <sub>FE1</sub>	60 to 120	100 to 200	160 to 320

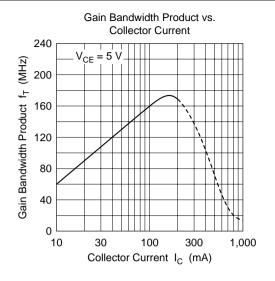


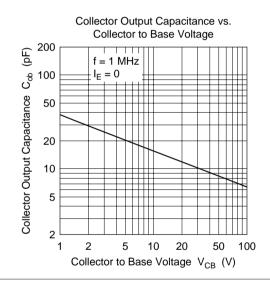




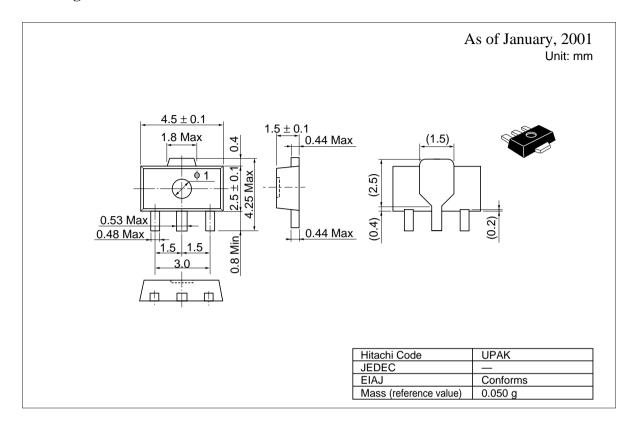








# **Package Dimensions**



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